

DP3407Q P-Channel Enhancement Mode Field Effect Transistor

General description

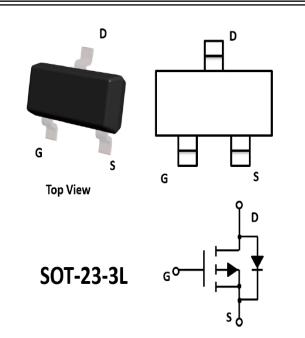
P-Channel Enhancement Mode Field Effect Transistor

Features:

- V_{DS} (V) =-30V I_D =-4.1 A
- $R_{DS(ON)} < 60 m\Omega$ (V $_{GS}$ =-10 V)
- $R_{DS(ON)} < 90 \text{m}\Omega \text{ (V}_{GS} = -4.5 \text{V)}$
- Trench Power LV MOSFET technology
- High density cell design for Low RDS(ON)
- High Speed switching
- Battery protection
- Load switch
- Power management

Device Marking:

Device Type	Marking	Shipping		
DP3407Q	A7**	3,000/Reel		



Absolute Maximum Ratings (TA=25°Cunless otherwise noted)

Parameter		Symbol	Maximum	Unit
Drain-source Voltage		V _{DS}	-30	V
Gate-source Voltage		V _{GS}	±20	V
Drain Current	T _A =25℃ @ Steady State	ID	-4.1	Α
	T _A =70℃ @ Steady State	-	-3.2	
Pulsed Drain Current ^A		Ірм	-15	Α
Total Power Dissipation @ T _A =25 ℃		P _D	1.5	W
Thermal Resistance Junction-to-Ambient @ Steady State ^B		Reja	82	°C/W
Junction and Storage Temperature Range		Тл ,Тѕтс	-55∼+150	°C

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DP3407Q



Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =-250μA	-30			V
Zero Gate Voltage Drain Current	Ipss	V _{DS} =-30V,V _{GS} =0V,T _C =25°C			-1	μΑ
Gate-Body Leakage Current	I _{GSS}	V_{GS} = ± 20 V, V_{DS} =0V			±100	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =-250μA	-1.0	-1.6	-2.4	V
Static Drain-Source On-Resistance	RDS(ON)	V _{GS} = -10V, I _D =-4.1A		40	60	mΩ
		V _{GS} = -4.5V, I _D =-3.5A		55	90	
Diode Forward Voltage	V _{SD}	I _S =-4.1A,V _{GS} =0V		-0.8	-1.2	V
Maximum Body-Diode Continuous Current	Is				-4.1	А
Dynamic Parameters						
Input Capacitance	Ciss	V _{DS} =-15V,V _{GS} =0V,f=1MHZ		580		pF
Output Capacitance	Coss			98		
Reverse Transfer Capacitance	C _{rss}			74		
Switching Parameters					1	
Total Gate Charge	Qg	V _{GS} =-10V,V _{DS} =-15V,I _D =-4.1A		6.8		
Gate Source Charge	Q _{gs}			1.0		nC
Gate Drain Charge	Q_{gd}			1.4		
Turn-on Delay Time	t D(on)	V_{GS} =-10V, V_{DD} =-15V, R_L =15 Ω , I_D =-1A, R_{GEN} =2.5 Ω		14		- ns
Turn-on Rise Time	t _r			61		
Turn-off Delay Time	t _{D(off)}			19		
Turn-off Fall Time	t _f			10		

A. Pulse Test: Pulse Width \leq 300us,Duty cycle \leq 2%.

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B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.



Typical Performance Characteristics

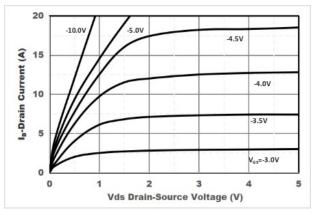


Figure 1. Output Characteristics

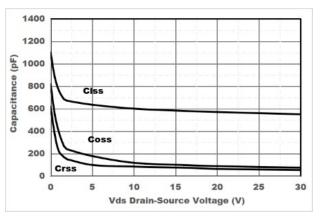


Figure 3. Capacitance Characteristics

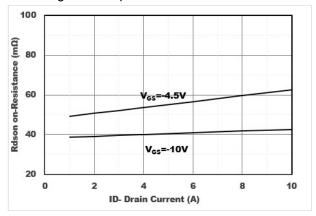


Figure 5. Drain-Source on Resistance

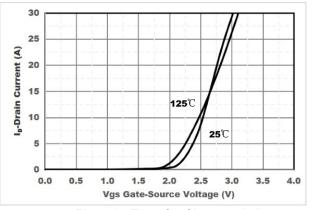


Figure 2. Transfer Characteristics

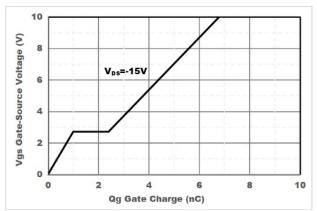


Figure 4. Gate Charge

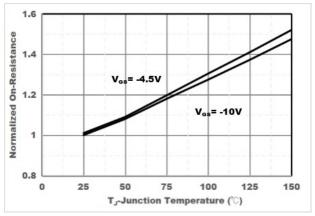


Figure 6. Drain-Source on Resistance

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